TOSHIBA Field Effect Transistor Silicon N Channel MOS Type (Ultra-High-Speed U-MOSⅢ)

# TK55D10J1

## **Switching Regulator Applications**

High-Speed switching

• Low gate charge: Q<sub>g</sub> = 110 nC (typ.)

• Low drain-source ON resistance:  $R_{DS (ON)} = 8.4 \text{ m}\Omega \text{ (typ.)}$ 

High forward transfer admittance: |Y<sub>fs</sub>| = 110 S (typ.)

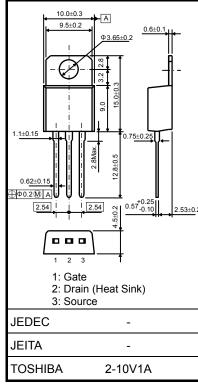
Low leakage current: I<sub>DSS</sub> = 10 μA (max) (V<sub>DS</sub> = 100 V)

• Enhancement mode:  $V_{th}$  = 1.1 to 2.3 V ( $V_{DS}$  = 10 V,  $I_D$  = 1 mA)

# Absolute Maximum Ratings (Ta = 25°C)

Characteristics			Symbol	Rating	Unit
Drain-source voltage			$V_{DSS}$	100	V
Drain-gate voltage ( $R_{GS} = 20 \text{ k}\Omega$ )			$V_{DGR}$	100	V
Gate-source voltage			$V_{GSS}$	±20	V
Drain current	DC	(Note 1)	I <sub>D</sub>	55	А
	Pulse	(Note 1)	$I_{DP}$	210	A
Drain power dissipation (Tc = 25°C)			$P_{D}$	140	W
Single pulse avalanche energy (Note 2)			E <sub>AS</sub>	382	mJ
Avalanche current			I <sub>AR</sub>	55	Α
Repetitive avalanche energy (Note 3)			E <sub>AR</sub>	9.4	mJ
Channel temperature			T <sub>ch</sub>	150	°C
Storage temperature range			T <sub>stg</sub>	-55 to 50	°C

Unit: mm



Weight: 1.35 g (typ.)

Note: Using continuously under heavy loads (e.g. the application of high temperature/current/voltage and the significant change in temperature, etc.) may cause this product to decrease in the reliability significantly even if the operating conditions (i.e. operating temperature/current/voltage, etc.) are within the absolute maximum ratings. Please design the appropriate reliability upon reviewing the Toshiba Semiconductor Reliability Handbook ("Handling Precautions"/"Derating Concept and Methods") and individual reliability data (i.e. reliability test report and estimated failure rate, etc).

#### **Thermal Characteristics**

Characteristics	Symbol	Max	Unit
Thermal resistance, channel to case	R <sub>th (ch-c)</sub>	0.89	°C/W
Thermal resistance, channel to ambient	R <sub>th (ch-a)</sub>	83.3	°C/W

Note 1: Ensure that the channel and lead temperatures do not exceed 150°C.

Note 2:  $V_{DD}=25$  V,  $T_{ch}=25^{\circ}C,\,L=200~\mu\text{H},\,I_{AR}=55~\text{A}$  ,  $R_{G}=1\Omega$ 

Note 3: Repetitive rating: pulse width limited by maximum channel temperature

This transistor is an electrostatic-sensitive device. Handle with care.

#### **Internal Connection**



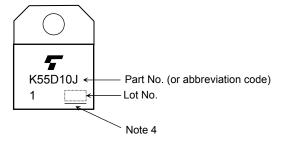
# **Electrical Characteristics (Ta = 25°C)**

Chara	cteristics	Symbol	Test Condition	Min	Тур.	Max	Unit
Gate leakage current		I <sub>GSS</sub>	$V_{GS} = \pm 16 \text{ V}, V_{DS} = 0 \text{ V}$	_	_	±10	μА
Drain cut-OFF cui	rent	I <sub>DSS</sub>	V <sub>DS</sub> = 100 V, V <sub>GS</sub> = 0 V	_	_	10	μΑ
Drain-source breakdown voltage		V (BR) DSS	$I_D = 10 \text{ mA}, V_{GS} = 0 \text{ V}$	100	_		V
		V (BR) DSX	$I_D = 10 \text{ mA}, V_{GS} = -20 \text{ V}$	55	_		
Gate threshold vo	Itage	V <sub>th</sub>	V <sub>DS</sub> = 10 V, I <sub>D</sub> = 1 mA	1.1	_	2.3	V
Drain-source ON resistance		R <sub>DS</sub> (ON)	$V_{GS} = 4.5 \text{ V}, I_D = 27A$	_	9.0	12.0	- mΩ
			V <sub>GS</sub> = 10 V, I <sub>D</sub> = 27A	_	8.4	10.5	
Forward transfer admittance		Yfs	$V_{DS} = 10 \text{ V}, I_D = 27 \text{ A}$	55	110		S
Input capacitance		C <sub>iss</sub>		_	5700		pF
Reverse transfer capacitance		C <sub>rss</sub>	$V_{DS} = 10V, V_{GS} = 0 V, f = 1 MHz$		390		
Output capacitance		C <sub>oss</sub>			1000		
Switching time F	Rise time	t <sub>r</sub>	$V_{GS}$ $0 V$ $V_{GS}$ $0 V$ $V_{DD} \simeq 50 V$	_	7	_	
	Turn-ON time	t <sub>on</sub>		_	30	_	ns
	Fall time	t <sub>f</sub>		_	20		115
	Turn-OFF time	t <sub>off</sub>	Duty ≤ 1%, t <sub>W</sub> = 10 μs	_	130		
Total gate charge (gate-source plus gate-drain)		Qg	$V_{DD} \simeq 80 \text{ V}, V_{GS} = 5 \text{ V}, I_D = 55 \text{A}$	_	63		
			$V_{DD} \simeq 80 \text{ V}, V_{GS} = 10 \text{ V}, I_D = 55\text{A}$	_	110	_	<u> </u>
Gate-source charge 1		Q <sub>gs1</sub>		_	17	_	nC
Gate-drain ("miller") charge		Q <sub>gd</sub>	$V_{DD} \simeq 80 \text{ V}, V_{GS} = 10 \text{ V}, I_D = 55\text{A}$	_	32	_	
Gate switch charge		Q <sub>SW</sub>		_	38	_	

# Source-Drain Ratings and Characteristics (Ta = 25°C)

Characteristics	Symbol	Test Condition	Min	Тур.	Max	Unit
Continuous drain reverse current (Note 1)	$I_{DR}$	_	_	_	55	Α
Pulse drain reverse current (Note 1)	I <sub>DRP</sub>	_	_	_	220	Α
Forward voltage (diode)	V <sub>DSF</sub>	I <sub>DR</sub> = 55 A, V <sub>GS</sub> = 0 V	_	-0.9	-1.2	V
Reverse recovery time	t <sub>rr</sub>	$I_{DR} = 55 \text{ A}, V_{GS} = 0 \text{ V},$	_	67	_	ns
Reverse recovery charge	Qrr	dI <sub>DR</sub> /dt = 50 A/μs	_	84	_	nC

# Marking

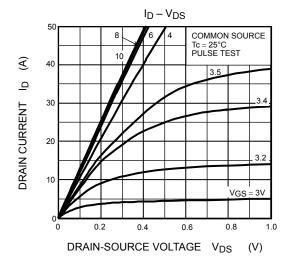


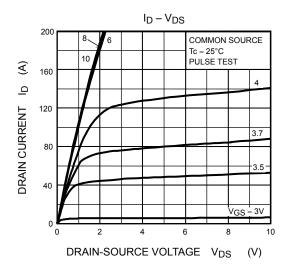
Note 4: A line under a Lot No. identifies the indication of product Labels.

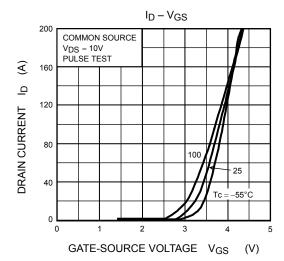
Not underlined: [[Pb]]/INCLUDES > MCV

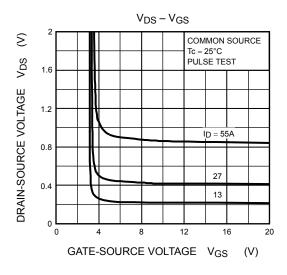
Underlined: [[G]]/RoHS COMPATIBLE or [[G]]/RoHS [[Pb]]

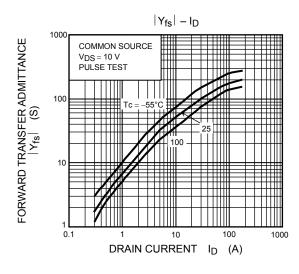
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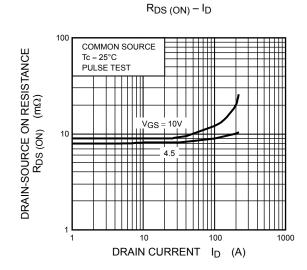


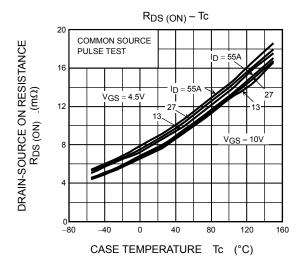


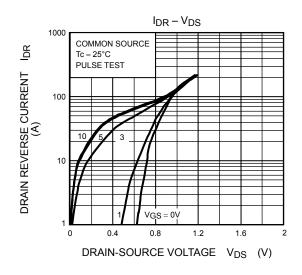


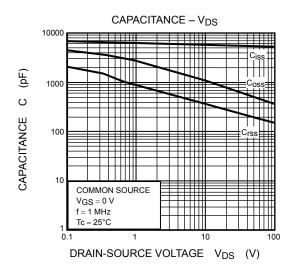


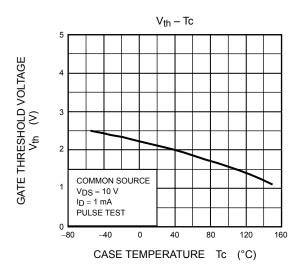


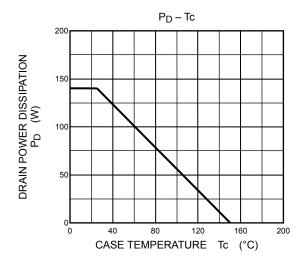


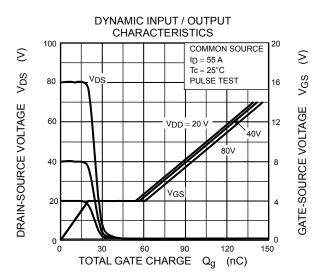


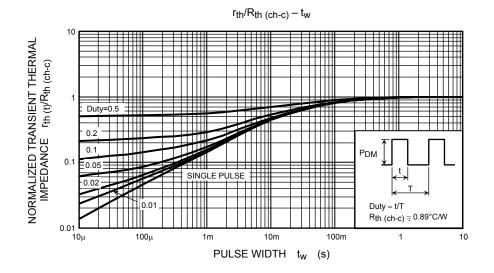


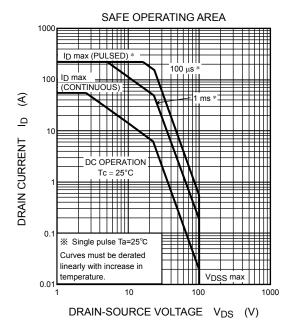


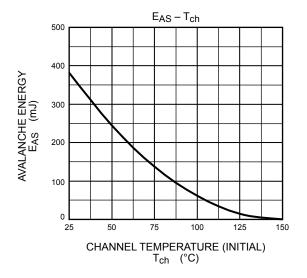


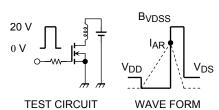












$$\begin{aligned} R_G &= 1\Omega \\ V_{DD} &= 25 \text{ V, } L = 200 \mu H \end{aligned} \qquad E_{AS} = \frac{1}{2} \cdot L \cdot I^2 \cdot \left( \frac{BVDSS}{BVDSS} - V_{DD} \right) \end{aligned}$$

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